








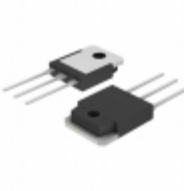
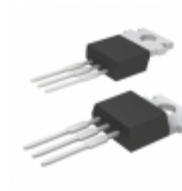
	<h2 style="color: red;">GP1M016A060H</h2>	
	Hersteller-Teilenummer:	GP1M016A060H
	Hersteller / Marke:	Global Power Technologies Group
	Teil der Beschreibung:	MOSFET N-CH 600V 16A TO220
Datenblätter:	 GP1M016A060H.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 2000 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	GP1M016A060H
Hersteller	Global Power Technologies Group
Beschreibung	MOSFET N-CH 600V 16A TO220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2000 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220
Verlustleistung (max)	290W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16A (Tc)
Rds On (Max) @ Id, Vgs	470 mOhm @ 8A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	53nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3039pF @ 25V
Verpackung	Tube

GP1M016A060H ist neu im Original, Suche GP1M016A060H Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie GP1M016A060H Global Power Technologies Group mit Garantie und Vertrauen. Anfrage GP1M016A060H: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>GP1M016A060F Global Power Technologies Group MOSFET N-CH 600V 16A TO220F</p>	 <p>GP1M016A025FG Global Power Technologies Group MOSFET N-CH 250V 16A TO220F</p>	 <p>GP1M018A020CG Global Power Technologies Group MOSFET N-CH 200V 18A DPAK</p>	 <p>GP1M016A025PG Global Power Technologies Group MOSFET N-CH 250V 16A IPAK</p>
 <p>GP1M016A025HG Global Power Technologies Group MOSFET N-CH 250V 16A TO220</p>	 <p>GP1M016A060FH Global Power Technologies Group MOSFET N-CH 600V 16A TO220F</p>	 <p>GP1M016A060N Global Power Technologies Group MOSFET N-CH 600V 16A TO3PN</p>	 <p>GP1M018A020HG Global Power Technologies Group MOSFET N-CH 200V 18A TO220</p>

heiße Teile

Mehr

 GP1FA553TZ0F	 GP1FAV31TK0F	 GP1FAV50RK0F	 GP1FAV50TK0F	 GP1FAV51TK0F
 GP1FD320TP0F	 GP1FM313TMF5	 GP1FM313TZMF	 GP1FSV51TK0F	 GP1L53VJ000F
 GP1L57J0000F	 GP1M003A050FG	 GP1M003A080CH	 GP1M003A090C	 GP1M006A070FH
 GP1M007A090H	 GP1M008A025PG	 GP1M009A020FG	 GP1M009A090N	 GP1M010A060H
 GP1M010A080FH	 GP1M011A050FH	 GP1M013A050H	 GP1M016A025CG	 GP1M016A060F
 GP1S092HCPI	 GP1S092HCPIF	 GP1S092HCPIF	 GP1S092HCPKF	 GP1S093HCZ
 GP1S093HCZ0F	 GP1S093HCZ0F	 GP1S093HCZ0F	 GP1S094HCZ0F	 GP1S094HCZ0F
 GP1S094HCZ0F	 GP1S096HCZ	 GP1S096HCZ0F	 GP1S096HCZ0F	 GP1S097HCZ0F
 GP1S194HCZ0F	 GP1S194HCZ0F	 GP1S195HCPS4	 GP1S195HCPSF	 GP1S196HCCSF
 GP1S196HCPSF	 GP1S196HCPSF	 GP1S196HCPSF4	 GP1S196HCZ0F	 GP1S196HCZO

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